

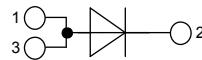
Standard Rectifier

Single Diode

V_{RRM} = 800 V
I_{FAV} = 10 A
V_F = 1.01 V

Part number**DLA 10 IM 800 UC**

Marking on Product: MARLUI



Backside: cathode

E72873

Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification

Package:

- Housing: TO-252 (DPak)
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

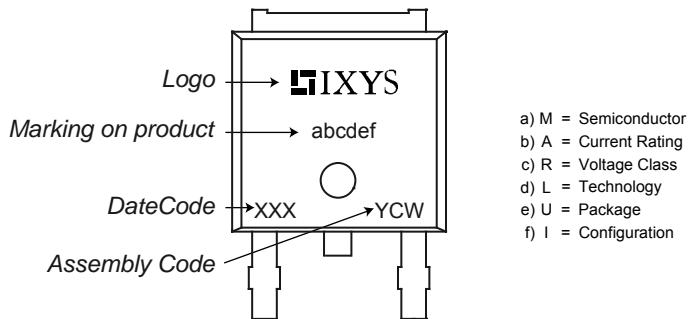
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	Unit
V _{RRM}	max. repetitive reverse voltage	T _{VJ} = 25°C			800	V
I _R	reverse current	V _R = 800 V T _{VJ} = 25°C V _R = 800 V T _{VJ} = 150°C			10 0.1	μA mA
V _F	forward voltage	I _F = 10 A T _{VJ} = 25°C			1.10	V
		I _F = 20 A			1.20	V
		I _F = 10 A T _{VJ} = 150°C			1.01	V
		I _F = 20 A			1.10	V
I _{FAV}	average forward current	rectangular, d = 0.5 T _C = 140°C			10	A
V _{F0} r _F	threshold voltage slope resistance }	for power loss calculation only T _{VJ} = 175°C			0.80	V
					15	mΩ
R _{thJC}	thermal resistance junction to case				3.15	K/W
T _{VJ}	virtual junction temperature		-55		175	°C
P _{tot}	total power dissipation	T _C = 25°C			45	W
I _{FSM}	max. forward surge current	t = 10 ms (50 Hz), sine T _{VJ} = 45°C			80	A
		t = 8,3 ms (60 Hz), sine V _R = 0 V			88	A
		t = 10 ms (50 Hz), sine T _{VJ} = 150°C			72	A
		t = 8,3 ms (60 Hz), sine V _R = 0 V			80	A
I ² t	value for fusing	t = 10 ms (50 Hz), sine T _{VJ} = 45°C			37	A ² s
		t = 8,3 ms (60 Hz), sine V _R = 0 V			37	A ² s
		t = 10 ms (50 Hz), sine T _{VJ} = 150°C			31	A ² s
		t = 8,3 ms (60 Hz), sine V _R = 0 V			32	A ² s
C _J	junction capacitance	V _R = tbd V; f = 1 MHz T _{VJ} = 25°C		tbd		pF

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
I_{RMS}	RMS current	per pin ¹⁾			20	A
R_{thCH}	thermal resistance case to heatsink			0.50		K/W
T_{stg}	storage temperature		-55		150	°C
Weight				0.3		g
F_c	mounting force with clip		20		60	N

¹⁾ I_{RMS} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

Product Marking



Part number

- | | |
|-----------------------|---------------------------|
| a) M = Semiconductor | D = Diode |
| b) A = Current Rating | L = Standard Rectifier |
| c) R = Voltage Class | A = (up to 1200V) |
| d) L = Technology | 10 = Current Rating [A] |
| e) U = Package | IM = Single Diode |
| f) I = Configuration | 800 = Reverse Voltage [V] |
| | UC = TO-252AA (DPak) |

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DLA 10 IM 800 UC	MARLUI	Tape & Reel	2500	503668

Outlines TO-252 (DPak)

